

IN THE U.S. PATENT AND TRADEMARK OFFICE



Applicant: Kazumasa HIRAMATSU et al. Conf.: 5987

App. No.: 09/522,707 Group: 2815

Filed: March 10, 2000 Examiner: Baumeister, B.

For: III-V COMPOUND SEMICONDUCTOR

Handwritten: 2015 #7/B [signature] 10/18/01

Adjustment date: 10/03/2001 FFANAEIA
10/02/2001 FFANAEIA 00000133 09522707
01 FC:128 -1890.00 OP

AMENDMENT

Assistant Commissioner for Patents
Washington, DC 20231

October 1, 2001

Sir:

In response to the Non-Responsive Communication that issued March 29, 2001, the period for response having been extended five months, the following amendments and remarks are submitted in connection with the above-identified application.

AMENDMENTS

10/02/2001 FFANAEIA 00000133 09522707
01 FC:128 1890.00 OP

IN THE WRITTEN DESCRIPTION:

Please amend the written description as follows.

Please replace the paragraph starting at page 6, line 6 with the following:

--Figure 1 is a cross-sectional view showing how regrowth proceeds on a pattern according to the prior art.--

Please replace the indentation starting at page 6, line 12 with the following:

--The denotations used in figure 1 are as follows.

TECHNOLOGY CENTER 2000

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10/03/2001

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Handwritten: B1

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